





Introduction to Mechanics of Materials 1. Basic concepts of mechanics, stress and strain, deformation, strength and fracture Monday Jan 8, 09-10:30am Introduction to Classical Molecular Dynamics 2. Introduction into the molecular dynamics simulation; numerical techniques Tuesday Jan 9, 09-10:30am **Mechanics of Ductile Materials** 3. Dislocations; crystal structures; deformation of metals Tuesday Jan 16, 09-10:30am The Cauchy-Born rule 4. Calculation of elastic properties of atomic lattices Friday Jan 19, 09-10:30am **Dynamic Fracture of Brittle Materials** 5. Nonlinear elasticity in dynamic fracture, geometric confinement, interfaces Wednesday Jan 17, 09-10:30am **Mechanics of biological materials** 6. Monday Jan. 22, 09-10:30am Introduction to The Problem Set 7. Atomistic modeling of fracture of a nanocrystal of copper. Wednesday Jan 22, 09-10:30am Size Effects in Deformation of Materials 8. Size effects in deformation of materials: Is smaller stronger? Friday Jan 26, 09-10:30am





- Pre-processing (define geometry, build crystal etc.)
- 2. Energy relaxation (minimization)
- 3. Annealing (equilibration at specific temperature)
- 4. "Actual" calculation; e.g. apply loading to crack
- 5. Analysis













## **Hydrogen bonding** e.g. between O and H in $H_2O$ Between N and O in proteins...

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See: http://www.columbia.edu/cu/biology/courses/c2005/images/3levelpro.4.p.jpg







Figure by MIT OCW. After Ackbarow and Buehler, 2007.







Titin I27 domain: Very resistant to unfolding due to parallel Hbonded strands

Image removed due to copyright restrictions.











# Fracture at ultra small scales Size effects





- Failure mechanism of ultra small brittle single crystals as a function of material size
- Properties of adhesion systems as a function of material size: Is Griffith's model for crack nucleation still valid at nanoscale?







• Inglis (~1910): Stress infinite close to a elliptical inclusion once shape is crack-like

"Inglis paradox": Why does crack not extend, despite infinitely large stress at even small applied load?

• Resolved by Griffith (~ 1950): Thermodynamic view of fracture

G = 2γ

"Griffith paradox": Fracture at small length scales? Critical applied stress for fracture infinite in small (nano-)dimensions ( $\xi$ =O(nm))!

### Considered here

Infinite peak stress







## Thin strip geometry





Figure by MIT OCW.

Change in potential energy: Create a "relaxed" element from a "strained" element, per unit crack advance

$$W_P = W_P(\sigma, a, \dots)$$









## Thin strip geometry





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## Fracture of thin strip geometry Theoretical considerations





 $\xi$ .. size of material



## Fracture of thin strip geometry Theoretical considerations



Stress for spontaneous crack propagation  $\sqrt{4 \cdot E}$ 

$$\sigma_f = \sqrt{\frac{4\gamma L}{\xi(1 - \nu^2)}}$$

Length scale  $\xi_{\rm cr}\, {\rm at}\, \sigma_{\rm th}\, {\rm cross-over}$ 

 $\xi$ .. size of material

$$\xi_{cr} = \frac{4\gamma E}{\sigma_{th}^2 (1 - v^2)}$$



Figure by MIT OCW.





Transition from Griffith-governed failure to maximum strength of material

- Griffith theory breaks down below a critical length scale
- Replace Griffith concept of energy release by failure at homogeneous stress





Bulk (harmonic, FCC)

$$\phi(r) = a_0 + \frac{1}{2}k_0(r - r_0)^2 \qquad \begin{array}{l} r_0 = 2^{1/6} \\ a \approx 1.587 \end{array} \qquad k_0 = 572.0$$
$$\mu = \frac{r_0^2}{2}k_0 \qquad E = 8/3\mu \qquad v = 1/3$$

$$h_{cr} = \frac{4\gamma E}{\sigma_{th}^2 (1 - v^2)}$$

### Interface (LJ) "dispersive-glue interactions"



Choose *E* and  $\gamma$  such that length scale is in a regime easily accessible to MD





 $\sigma_f = \sigma_{th}$  Failure at theor. strength



 $\sigma_f = \sqrt{\frac{4\gamma E}{h(1 - v^2)}}$ 

Griffith-governed failure

Figure by MIT OCW.

$$\xi_{cr} = \frac{4\gamma E}{\sigma_{th}^2 (1 - v^2)}$$

Atomistic simulation indicates:

At critical nanometer-length scale, structures become insensitive to flaws: Transition from <u>Griffith governed failure</u> to <u>failure at theoretical strength</u>, independent of presence of crack!!

(Buehler et al., MRS Proceedings, 2004; Gao, Ji, Buehler, MCB, 2004)





Figure by MIT OCW.

# Summary: Small-scale structures for strength optimization & flaw tolerance







# Can this concept explain the design of biocomposites in bone?







## Adhesion of Geckos





### Autumn et al., PNAS, 2002



Courtesy of National Academy of Sciences, U.S.A. Used with permission.

Source: Autumn, Kellar, Metin Sitti, Yiching A. Liang, Anne M. Peattie, Wendy R. Hansen, Simon Sponberg, Thomas W. Kenny, Ronald Fearing, Jacob N. Israelachvili, and Robert J. Full. "Evidence for van der Waals adhesion in gecko setae." *PNAS* 99 (2002): 12252-12256.

(c) National Academy of Sciences, U.S.A.

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• Schematic of the model used for studies of adhesion: The model represents a cylindrical Gecko spatula with radius attached to a rigid substrate.

• A circumferential crack represents flaws for example resulting from surface roughness. The parameter denotes the dimension of the crack.



# Equivalence of adhesion and fracture problem





Figure by MIT OCW.



# Equivalence of adhesion and fracture problem





Figure by MIT OCW.

Energy release rate  $K_I = \sqrt{\frac{\pi}{8}} R_{cr} \sigma^2$   $G = \frac{K_I^2}{E'} = \frac{\pi}{8} \frac{R_{cr}}{E'} \sigma^2$   $G = 2\gamma = \Delta \gamma$ Adhesion energy

## Theoretical considerations Adhesion problem as fracture problem





$$K_{I} = \frac{P}{\pi a^{2}} \sqrt{\pi a} F_{1}(\alpha) \qquad \frac{K_{I}^{2}}{2E^{*}} = \Delta \gamma$$
$$\beta = \sqrt{2/(\pi \alpha F_{1}^{2}(\alpha))}$$
$$E^{*} = E/(1-v^{2})$$

Function (tabulated)

$$R_{cr} = \beta^2 \frac{\Delta \gamma E^*}{\sigma_{th}^2}$$

$$R_{cr} \sim 225 nm$$

Typical parameters for Gecko spatula





Three-dimensional model



LJ: Autumn *et al*. have shown dispersive interactions govern adhesion of attachment in Gecko



# Stress close to detachment as a function of adhesion punch size



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Has major impact on adhesion strength: At small scale no stress magnification

#### Smaller size leads to homogeneous stress distribution





$$R_{cr} = \frac{8}{\pi} \frac{E^* \Delta \gamma}{\sigma_{th}^2}$$

#### The ratio

 $\sqrt{R_{cr}/R}$ 

governs adhesion strength

- Results agree with predictions by scaling law
- Variations in Young's modulus or  $\gamma$  may also lead to optimal adhesion

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### Single punch

$$z = -\psi \frac{2\sigma_{th}R}{\pi E/(1-\nu^2)} \left[ \ln(1-\overline{r}^2) + \overline{r}\ln\left(\frac{1+\overline{r}}{1-\overline{r}}\right) \right]$$

Concept: Shape parameter  $\psi$ 

### Periodic array of punches

$$z = -\psi \frac{2\sigma_{th}R}{\pi E/(1-\nu^2)} \left\{ \left[ \ln\left(1-\overline{r}^2\right) + \overline{r}\ln\left(\frac{1+\overline{r}}{1-\overline{r}}\right) \right] \right\}$$

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$$-\sum_{n=1}^{\infty} \left[ ln \left( \frac{(2n\lambda + \overline{r})^2 - 1}{(2n\lambda)^2 - 1} \right) + (2n\lambda + \overline{r}) ln \left( \frac{2n\lambda + \overline{r} + 1}{2n\lambda + \overline{r} - 1} \right) - 2n\lambda ln \left( \frac{2n\lambda + 1}{2n\lambda - 1} \right) \right]$$
PBCs

$$-\sum_{n=1}^{\infty}\left[\ln\left(\frac{(2n\lambda-\bar{r})^2-1}{(2n\lambda)^2-1}\right)+(2n\lambda-\bar{r})\ln\left(\frac{2n\lambda-\bar{r}+1}{2n\lambda-\bar{r}-1}\right)-2n\lambda\ln\left(\frac{2n\lambda+1}{2n\lambda-1}\right)\right]\right\}$$

Derivation: Concept of superposition to negate the singular stress





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The shape function defining the surface shape change as a function of the shape parameter  $\psi$ . For  $\psi=1$ , the optimal shape is reached and stress concentrations are predicted to disappear.







Figure by MIT OCW.

**Strategy**: Displace atoms held rigid to achieve smooth surface shape





Figure removed due to copyright restrictions.



 $\psi$ =1: Optimal shape



## Robustness of adhesion



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- By finding an optimal surface shape, the singular stress field vanishes.
- However, we find that this strategy does not lead to robust adhesion systems.

• For robustness, shape reduction is a more optimal way since it leads to (i) vanishing stress concentrations, and (ii) tolerance with respect to surface shape changes.




- We used a systematic atomistic-continuum approach to investigate brittle fracture and adhesion at ultra small scales
- We find that Griffith's theory breaks down below a critical length scale
- Nanoscale dimensions allow developing extremely strong materials and strong attachment systems: Nano is robust

Small nano-substructures lead to robust, flaw-tolerant materials. In some cases, Nature may use this principle to build strong structural materials.

- Unlike purely continuum mechanics methods, MD simulations can intrinsically handle stress concentrations (singularities) well and provide accurate descriptions of bond breaking
- Atomistic based modeling will play a significant role in the future in the area of modeling nano-mechanical phenomena and linking to continuum mechanical theories as exemplified here.





# Chemical complexity: Modeling chemical reactions

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 Empirical potentials: Treatment of large molecular systems to capture inhomogeneities at nanoscale;
 >10,000 atoms

**Dilemma:** Many empirical potentials can not describe chemistry accurately (bond breaking, formation, ...)

Images removed due to copyright restrictions. Illustration of reaction: ethane to ethylene.

**Nonreactive models:** Require *a priori* knowledge of chemical state of atoms + connectivity: **Severely limits solution space** 





Nonreactive FF:

"Harmonic spring"

$$\phi = \frac{1}{2}k(r-r_0)^2$$

 $r_0$  EQ distance between atoms

k Spring constant

Constant valency (available bonds)

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Atomic bond model: bond analogous to a spring. Bonds between 2 sp3, sp2, and sp1 atoms.

Reactive FF: 
$$\phi = \frac{1}{2}k(BO)(r - r_0(BO))^2$$
  
BO =  $f(r)$ 

1

Bond properties (bond stiffness k, EQ distance  $r_0$ ) are made dependent on bond order (BO)

BO is function of bond distance (Pauling): Theoretical link to quantum chemistry © 2007 Markus J. Buehler, CEE/MIT







Figure by MIT OCW.

**Difference between reactive and nonreactive model:** Reactive model capable of describing energetics of small and large deviation from equilibrium (key during instabilities, chemical reactions..)



- A bond length/bond order relationship is used to obtain smooth transition (Pauling) from non-bonded to single, double, and triple bonded systems.
- All connectivity-dependent interactions (*i.e.* valence and torsion angles) are made **bond-order dependent**: Ensures that their energy contributions disappear upon bond dissociation
- Feature **non-bonded interactions** (van der Waals, Coulomb): **Shielded**
- ReaxFF uses a geometry-dependent charge calculation scheme (similar to QEq) that accounts for polarization effects
- Many parameters in the formulation have physical meaning



# Charge equilibration



Images removed due to copyright restrictions. Molecular models with each atom's charge labeled, comparing ReaxFF-calculated charges with actual.

# Charges in ReaxFF are not fixed, but can flow, depending on local environment:

- Assign one electronegativity and hardness to each element; optimize these parameters against QM-charge distributions

- Use system geometry in solving electronegativity equilibration equations in every iteration

# ReaxFF is highly transferable model

Image removed due to copyright restrictions. Periodic table showing which elements can be described by ReaxFF; these elements are: H, He, Li, B, C, N, O, F, Ne, Na, Mg, Al, Si, P, S, Cl, Ar, K, Ca, Ti, V, Fe, Co, Ni, Cu, Zn, Se, Rb, Y, Zr, Mo, Ru, Te, Pt, an Bi.

#### Published ReaxFF force fields for:

- H/C (van Duin, Dasgupta, Lorant and Goddard, JPC-A 2001, **105**, 9396; van Duin and Sinninghe Damste, Org. Geochem.2003, **34**, 515; Chen, Lusk, van Duin and Goddard PR-B 2005, **72**, 085416, Han, Kang, Lee, van Duin and Goddard Appl. Phys. Lett. 2005, **86**, 203108)

- Si/SiO2/SiC (van Duin, Strachan, Stewman, Zhang, Xu and Goddard, JPC-A 2003, **107**, 3803; Chenoweth, Cheung, van Duin, Goddard and Kober, JACS 2005, **127**, 7192; Buehler, van Duin and Goddard, PRL 2006, **96**, 095505)

- Nitramines/RDX/TATP (Strachan, van Duin, Chakraborty, Dasupta and Goddard, PRL 2003,**91**,09301; Strachan, van Duin, Kober and Goddard, JCP 2005,**122**,054502; Han, Strachan, van Duin and Goddard, in preparation; van Duin, Dubnikova, Zeiri, Kosloff and Goddard, JACS 2005, **127**, 11053)

- Al/Al2O3 (Zhang, Cagin, van Duin, Goddard, Qi and Hector, PRB 2004,69,045423)
- Ni/Cu/Co/C (Nielson, van Duin, Oxgaard, Deng and Goddard, JPC-A 2005, 109, 493)
- Pt/PtH (Ludwig, Vlachos, van Duin and Goddard, JPC-B 2006)
- Mg/MgH (Cheung, Deng, van Duin and Goddard, JPC-A 2005, 109, 851)

- BN-nanotubes (Han, Kang, Lee, van Duin and Goddard, JCP 2005, **123**,114703; Han, Kang, Lee, van Duin and Goddard, JCP 2005, **123**,114704)

- Li/LiC (Han, van Duin and Goddard, JPC-A 2005, 109, 4575)

A. Duin et al., 2001-2006



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**Idea:** Use concept of handshaking or overlap: Calculate set of properties with QM and ensure that ReaxFF reproduces these properties

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Image removed due to copyright restrictions. Graph showing that ReaxFF is 1,000,000 times faster than QM (DFT).

A. Duin et al., 2001-2006



# Concurrent multi-scale simulations







• Concurrent FE-atomistic-ReaxFF scheme in a crack problem (crack tip treated by ReaxFF) and an interface problem (interface treated by ReaxFF).

• Highlighted transition regions as handshake domains between different scale and methods.

Example for potential coupling: Concept of mixed Hamiltonian ("handshake")



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See figs. 1, 2, 3, 4 and 5 in Buehler, Markus J., Adri C. T. van Druin, and William Goddard III. "Multiparadigm Modeling of Dynamical Crack Propagation in Silicon Using a Reactive Force Field." Phys Rev Lett 96 (2006): 095505-1 - 4.

 $w_i = 1$ 

i=0...N





Reactive region expands during simulation Based on determination of reaction front M.J. Buehler, 2006, unpublished





Examples
 demonstrates
 the concept of
 the moving
 boundary
 between
 different
 computational
 engines

Boundary
 location
 determined by
 position of
 oxygen atoms:
 Automatic
 update



M.J. Buehler, 2006, unpublished



### Metal/metal oxide systems









#### Ni/Ni-O system

M.J. Buehler, 2006, unpublished





# **Dynamic fracture of silicon:** Hybrid multi-paradigm modeling of crack initiation, propagation and fracture instabilities





- We consider a crack in a single silicon crystal under remote mode I loading.
- We use periodic boundary conditions in the *z* direction corresponding to a plane strain case.
- The smallest system contains 13,000 atoms and the largest system over 110,000 atoms.
- In the largest system,  $L_x \approx 550$  Å and  $L_y \approx 910$  Å.
- The number of reactive atoms varies between 500 and 3,000.
- Calculation of forces and energies in the reactive region is the most expensive part

Buehler et al., Phys. Rev. Lett., 2006

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See figs. 1, 2, 3, 4 and 5 in Buehler, Markus J., Adri C. T. van Druin, and William Goddard III. "Multiparadigm Modeling of Dynamical Crack Propagation in Silicon Using a Reactive Force Field." *Phys Rev Lett* 96 (2006): 095505-1 - 4.





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(110 crack surface)

• Crack propagation with a pure Tersoff potential (left) and the hybrid ReaxFF-Tersoff scheme (right) along the [110] direction (energy minimization scheme).

• The snapshots are both taken with the same loading applied and after the same number of minimization steps. The systems contain 28,000 atoms and  $L_x \approx 270$  Å and  $L_v \approx 460$  Å.

Shows importance of large-strain properties as suggested earlier (Buehler *et al.*, Nature, 2003, Buehler and Gao, Nature, 2006)

Buehler et al., Phys. Rev. Lett., 2006





- To model cracking in Silicon more efficiently, we developed a multi-paradigm scheme that combines the Tersoff potential and ReaxFF
- The ReaxFF region is moving with the crack tip (region determined based on local atomic strain)

#### New hybrid scheme within CMDF

(110) crack surface, 10 % strain

Reactive region is moving with crack tip

Images removed due to copyright restrictions.

See figs. 1, 2, 3, 4 and 5 in Buehler, Markus J., Adri C. T. van Druin, and William Goddard III. "Multiparadigm Modeling of Dynamical Crack Propagation in Silicon Using a Reactive Force Field." *Phys Rev Lett* 96 (2006): 095505 -1 - 4.



• CMDF reproduces experimental results (e.g. Cramer, Wanner, Gumbsch, 2000) Buehler *et al.*, *Phys. Rev. Lett.*, 2006





Images removed due to copyright restrictions.

See figs. 1, 2, 3, 4 and 5 in Buehler, Markus J., Adri C. T. van Druin, and William Goddard III. "Multiparadigm Modeling of Dynamical Crack Propagation in Silicon Using a Reactive Force Field." *Phys Rev Lett* 96 (2006): 095505 -1 - 4.





Image removed due to copyright restrictions. Graph illustrating jump in crack speed at critical strain.



### Comparison: Experimental results



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See fig. 2 in Bernstein, N. and D. W. Hess. "Lattice Trapping Barriers to Brittle Fracture." *Phys Rev Lett* 91 (2003): 025501.

SW/EDIP can not reproduce this phenomenon

(Bernstein & Hess, *Phys. Rev. Lett.*, 2003)

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Courtesy of the American Physical Society.



SW/EDIP can not reproduce this phenomenon, CMDF can!



Figure by MIT OCW.







Breaking of first 6-membered ring

Initial crack structure

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## Atomistic mechanisms at onset of fracture: Formation of 5-7 rings





Formation of 7-5-ring combination

Also observed in TB calculations by Gabor Csanyi (Cambridge Univ.)



Rupture occurs ahead of 7membered ring ("micro-crack") © 2007 Markus J. Buehler, CEE/MIT









Crack propagation (creates smooth surface)

While crack propagates, formation of another 7-5 ring combination © 2007 Markus J. Buehler, CEE/MIT



# Atomistic mechanisms at onset of fracture





5-7 ring combination leads to change in crack direction, creating a slight surface step



Time (seconds) Instability sets in at ~66% of Rayleigh wave speed (assume  $c_R$ ~4.5 km/sec)

Close to experimental observation



### Atomistic mechanisms at onset of fracture





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	<ul> <li>Crack dynamics in silicon</li> </ul>
	without (subplots (a) and
	(c)) and with oxygen
Images removed due to copyright restrictions.	molecules present
	(subplots (b) and (d))
See figs. 1, 2, 3, 4 and 5 in Buehler, Markus J., Adri C. T. van Druin, and William Ge	oddard III.
"Multiparadigm Modeling of Dynamical Crack Propagation in Silicon Using a Reactive	
Phys Rev Lett 96 (2006): 095505 -1 - 4.	<ul> <li>Subplots (a) and (b) show</li> </ul>
	the results for 5 percent
	applied
	strain, whereas subplots
	(c) and (d) show the results
	for 10 percent applied
	strain.
	<b>T</b> I ( ) ( )
	<ul> <li>The systems contain</li> </ul>
	13,000 atoms and
	<i>Lx</i> ≈ 160 Å and <i>Ly</i> ≈ 310 Å.
Buehler <i>et al., Phys. Rev. Lett</i> ., 2006	© 2007 Markus J. Buehler, CEE/MIT





# Nanocrystalline materials

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- Similar considerations as for brittle materials and adhesion systems apply also to ductile materials
- In particular, the deformation mechanics of nanocrystalline materials has received significant attention over the past decade
  - Strengthening at small grain size (Hall-Petch effect)
  - Weakening at even smaller grain sizes after a peak

http://me.jhu.edu/~ dwarner/index\_file s/image003.jpg

Images removed due to copyright restrictions.





- It has been observed that the strength of polycrystalline materials increases if the grain size decreases
- The Hall-Petch model explains this by considering a dislocation locking mechanism:



Nucleate second source in other grain (right)

Physical picture: Higher external stress necessary to lead to large dislocation density in pileup

$$\sigma_{Y} \sim \frac{1}{\sqrt{d}}$$

See, e.g. Courtney, Mechanical Behavior of Materials





Different mechanisms have been proposed at nanoscale, including

• GB diffusion (even at low temperatures) – Wolf *et al*.

• GB sliding – Schiotz *et al*.

 GBs as sources for dislocations – van Swygenhoven, stable SF energy / unstable SF energy (shielding) Figure removed due to copyright restrictions. See p. 15 of http://www.imprs-am.mpg.de/summerschool2003/wolf.pdf



#### Review articles:

Yamakov V, **Wolf D**, Phillpot SR, et al. <u>Deformation-mechanism map for **nanocrystalline** metals by molecular-<u>dynamics simulation</u> **NATURE MATERIALS** 3 (1): 43-47 JAN 2004</u>

Van Swygenhoven H, Derlet PM, Froseth AG Stacking fault energies and slip in nanocrystalline metals NATURE MATERIALS 3 (6): 399-403 JUN 2004

#### Controversial debate about the mechanisms at ultra small scales

- □ Wolf *et al*.: Coble creep as deformation mechanism
- Van Swygenhoven and Schiotz suggest dislocation mechanisms to be active even to small grain sizes (even full dislocations) and grain boundary sliding or short range atomic rearrangements in the grain boundary